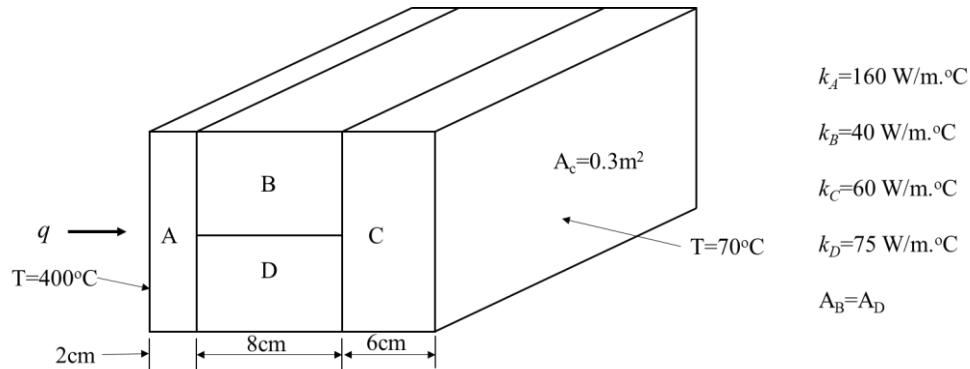


1. A 2.5cm thick solid block with a cross-sectional area of 0.2 m^2 has one side maintained at 35°C and the other at 100°C . The temperature at the center plane of the material is 66°C , and the rate of heat flow through the material is 2kW . Obtain an expression for the thermal conductivity of the material assuming a linear function of temperature.
2. Assuming one-dimensional heat flow, estimate the heat flux through the composite wall shown in Fig. 1. Is the assumption of 1d heat flow justified in this case.



3. One side of a copper block 6cm thick is maintained at 185°C . The other side is covered with a layer of fiberglass 2cm thick. The outside of the fiberglass layer is maintained at 80°C . For a heat flow rate of 250W through the composite slab, estimate the cross-sectional area of the slab normal to the direction of heat flow.

Given: $k_{\text{copper}} = 386 \text{ W/m.}^\circ\text{C}$ and $k_{\text{fiberglass}} = 0.035 \text{ W/m.}^\circ\text{C}$.

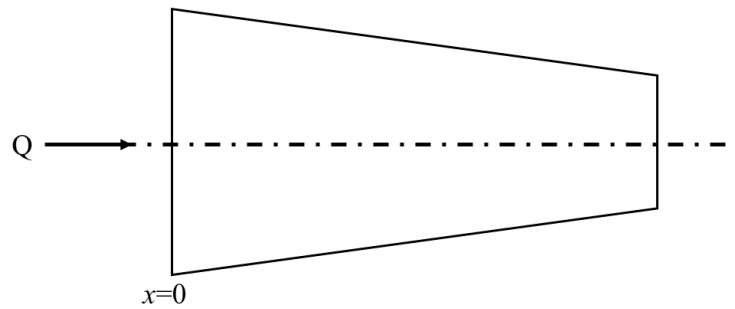
4. Heat flow occurs along the axis of a solid which has the shape of a truncated cone (see sketch) with circumferential surface insulated. The base is at 400°C and the area of the section at distance x measured from the base of the cone is given by

$$A = 1.5(1 - 1.7x) \text{ m}^2, \text{ where } x \text{ is in m.}$$

If the plane at $x = 0.3\text{m}$ is maintained at 150°C , determine

- a) Rate of heat flow
- b) Temperature at $x = 0.2\text{m}$
- c) Temperature gradient at the two surfaces i.e. at $x = 0$ and $x = 0.2\text{m}$.

Given: $k = 2.5 \text{ W/m }^\circ\text{C}$.



5. Consider a mass m of ice at the fusion temperature ($T_F = 0^\circ\text{C}$) that is enclosed in a cubical container of width (W) on a side. The container wall is of thickness L and thermal conductivity k . If the outer surface of the wall is heated to a temperature $T_1 > T_F$ to melt the ice, obtain an expression for the time needed to melt the entire mass of ice. State the assumptions.
6. A square silicon chip ($k = \text{W/m.K}$) is of width $w = \text{mm}$ on a side and of thickness $t = 1\text{mm}$. The chip is mounted in a substrate such that its side and back surfaces are insulated while the front is exposed to a coolant. If 6W are being dissipated in circuits mounted to the back surface of the chip, what is the steady state temperature difference between back and front surfaces.
7. A thin silicon chip and an 8mm thick aluminium substrate are separated by a 0.02mm thick epoxy joint. The chip and substrate are 20mm on a side and their exposed surfaces are cooled by air which is at a temperature of 25°C and provides a convection coefficient of $200\text{W}/(\text{m}^2)\text{K}$. If the chip dissipates heat at a rate $10^4\text{W}/\text{m}^2$ under normal conditions, will it operate below a maximum allowable temperature of 85°C ?
Given: thermal conductivity of aluminium = $239\text{W}/\text{m(K)}$ and the contact resistance of silicon chip/epoxy joint = $0.9 \times 10^{-4}\text{m}^2\text{K/W}$
8. Determine the density, specific heat, and thermal conductivity of lightweight aggregate concrete that is composed of 65% stone mix concrete and 35% air by volume. Evaluate properties at $T = 300\text{K}$.